Amendments to the Claims:

Claim 1 (currently amended): An apparatus used in planarizing a front surface of a wafer, comprising:

- a) an interferometer monitoring a front surface of a wafer,
- b) a multizone carrier having a plurality of independently controllable pressure plenums, wherein the earrier is adapted for pressing the front surface of the wafer against the polishing surface, said carrier comprising a plurality of concentric, independently pressurizable plenums, each of said plurality of plenums capable of containing a different, uniform pressure; and
- c) a control system in communication with the interferometer and the multizone carrier for varying the pressure in each of said plurality of plenums.

Claim 2 (original) The apparatus of claim 1 wherein the interferometer comprises a light source positioned to direct a light signal towards a front surface of a wafer and a detector positioned to capture the light signal towards a front surface of a wafer and a detector positioned to capture the light signal after reflecting off the front surface of the wafer.

Claim 3 (original) The apparatus of claim 1 wherein the interferometer comprises a plurality of light sources each positioned to direct a light signal towards a location on a front surface of a wafer and a plurality of corresponding detectors each positioned to capture one of the light signals reflected off the front surface of the wafer.



Claim 4 (original) The apparatus of claim 1 further comprising:

- d) a platen adapted for supporting the polishing surface; and
- c) a motion generator operably coupled to the platen.



Claim 5 (original) The apparatus of claim 4 wherein the motion generator is operably coupled to the platen to rotate the platen.

Claim 6 (original) The apparatus of claim 4 wherein the motion generator is operably coupled to the platen to orbit the platen.

Claim 7-10 (cancelled)

Claim 11 (currently amended): An apparatus used in planarizing a front surface of a wafer, comprising:

- a) a platen for supporting a polishing surface;
- b) a motion generator operably coupled to rotate the platen;
- a light source positioned in the platen to direct a light signal toward a front surface
 of a wafer;
- d) a detector position in the platen to capture the light signal after reflecting off the front surface of the wafer;
- e) a multizone carrier having a plurality of concentric, independently controllable
 pressure plenums, wherein the carrier is adapted for pressing the front surface of the
 wafer against the polishing surface; and
- f) a control system in communication with the light source, the detector and the multizone carrier for adjusting the pressure in each of said plurality of concentric, independently controllable pressure plenums.

Claim 12 (original) The apparatus of claim 11 wherein the light source comprises a laser and the detector comprises an interferometer.

Claim 13 (original) The apparatus of claim 12 further comprising a second laser and a second interferometer.



Claim 14 (currently amended) An apparatus used in planarizing the front surface of a wafer, comprising:

- a) the temperature probe monitoring the front surface of a wafer,
- a multizone carrier having a plurality of concentric, independently controllable pressure plenums, wherein the carrier is adapted for pressing the front surface of the wafer against the polishing surface; and
- c) a control system in communication with the temperature probe and the multizone carrier for adjusting the pressure in each of the independently controllable pressure plenums.

Claim 15 (currently amended) An apparatus used in planarizing the front surface of a wafer, comprising:

- a) an eddy current probe monitoring a front surface of wafer;
- a multizone carrier having a plurality of <u>concentric</u>, independently controllable pressure plenums, wherein the carrier is adapted for pressing the front surface of the wafer against a polishing surface; and
- c) a control system in communication with the eddy current probe and the multizone carrier for adjusting the pressure in each of said independently controllable pressure plenums.

Claims 16-20 (cancelled)



Claim 21 (currently amended) A method for planarizing a front surface of a wafer comprising the steps of:

- a) continuously pressing a front surface of a wafer mounted in a multizone carrier against a working surface during a planarization process, the multizone carrier comprising a plurality of concentric, independently pressurizable plenums;
- b) continuously generating relative motion between the front surface of the wafer and the working surface during the planarization process;
- c) transmitting a light signal to the front surface of the wafer;
- d) receiving an interference signal from the front surface of the wafer;
- e) calculating intensity measurements from the interference signals;
- f) correlating intensity measurements with radial positions on the front surface of the wafer;
- g) analyzing the intensity measurements and correlating radial positions;
- h) altering the planarization process adjusting the pressure in at least one of said plurality of plenums based on the analysis.

Claim 22 (original) The method of claim 21 wherein the relative motion between the front surface of the wafer and the working surface comprises rotating the working surface.

Claim 23 (original) The method of claim 21 further comprising the steps of:

g) repeating steps c) through h) until an endpoint condition has been detected.

Claim 24 (cancelled)



Claim 25 (currently amended) A method for planarizing a front surface of a wafer on a chemical mechanical polishing tool with a rotating working surface and a multizone carrier for holding the wafer and pressing it against the working surface, comprising the steps of:

- a) polishing a first wafer by continuously pressing a front surface of the wafer against the rotating working surface using a first set of carrier zone pressures;
- b) transmitting a plurality of sequential light signals to the front surface of the first wafer;
- receiving a plurality of reflected light signals from the front surface of the first wafer corresponding to the transmitted light signals;
- d) correlating the reflected light signals with radial positions on the front surface of the first wafer;
- e) determining a planarization condition of the front surface of the first wafer based on the reflected light signals and the radial positions thereof;
- f) adjusting the multizone earrier to a second set of carrier zone pressures based on the planarization condition of the first wafer;
- g) polishing a second wascr using the second set of carrier zone pressures:
- h) identifying a radial region of the first wafer that was overpolished relative to other regions of the wafer; and
- i) adjusting the carrier zonc pressures such that the lowest carrier pressure is substantially adjacent to the overpolished region of the first wafer.

Claim 26 (cancelled)





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Claim 27 (original) The method of claim 25 wherein the light signals in the step of transmitting a plurality of light signals are laser light signal.

Claim 28 (original) The method of claim 27 wherein the interferometer is used in step (c) for receiving the reflected light signals.